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APPLICANT FORREST et al.	
FILING DATE June 25, 2003	GROUP 18/5

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	PATENT/ PUBLICATION NUMBER	PATENT/ PUBLICATION DATE	NAME	CLASS	SUBCLASS	FILING DATE
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EO	5,256,205	October 26, 1993	Schmitt, III et al.			
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